SCS304AM

SiC Schottky Barrier Diode

Datasheet

V_R	650V
I _F	4A
Q_{C}	11nC

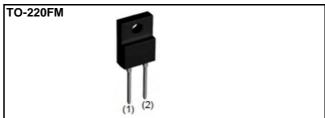
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

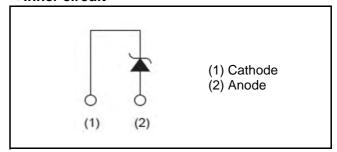
Applications

- PFC Boost Topology
- · Secondary Side Rectification
- Data Center
- PV Power Conditioners

Outline



•Inner circuit



Packaging specifications

- : donaging opcomoducione				
	Packaging	Tube		
	Reel size (mm)	-		
Typo	Tape width (mm)	-		
Type	Basic ordering unit (pcs)	50		
	Packing code	С		
	Marking	SCS304AM		

• Absolute maximum ratings $(T_i = 25^{\circ}C)$

	Parameter	Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V_{RM}	650	V
Reverse voltage (De	C)	V_R	650	V
Continuous forward	current (T _c = 130°C)	I _F	4	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		27	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C	al, T _j =150°C		А
current	PW=10μs square, T _j =25°C		100	А
Repetitive peak forward current		I _{FRM}	17 * ¹	А
1≦PW≦10ms, T _j =25°C		ſ.2	3.6	A ² s
i ² t value 1≦PW≦10ms, T _j =150°C		$\int i^2 dt$	2.4	A ² s
Total power disspation		P_{D}	26 *²	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

•Electrical characteristics $(T_j = 25^{\circ}C)$

Parameter Symbol	Symbol	Conditions	Values		Unit	
	Conditions	Min.	Тур.	Max.	Offic	
DC blocking voltage	V_{DC}	I _R =20μA	650	-	-	V
		I _F =4A,T _j =25°C	-	1.35	1.50	V
Forward voltage	V_{F}	I _F =4A,T _j =150°C	-	1.44	1.71	V
		I _F =4A,T _j =175°C	-	1.50	-	V
	I _R	V _R =650V,T _j =25°C	-	0.012	20	μΑ
Reverse current		V _R =650V,T _j =150°C	-	0.8	80	μΑ
		V _R =650V,T _j =175°C	-	2.4	-	μΑ
Total conscitones		V _R =1V,f=1MHz	-	200	-	pF
rotal capacitance	Total capacitance C	V _R =650V,f=1MHz	-	18	-	pF
Total capacitive charge	Q_{C}	V _R =400V,di/dt=350A/μs	-	11	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	14	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	48	-	mJ

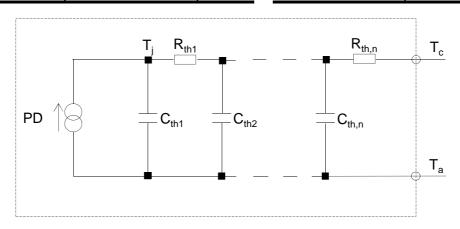
Thermal characteristics

Parameter	Symbol	ol Conditions	Values			Unit
Parameter	Symbol		Min.	Тур.	Max.	Offic
Thermal resistance	$R_{th(j-c)}$	-	-	4.9	5.7	°C/W

●Typical Transient Thermal Characteristics

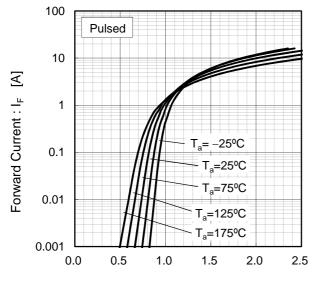
7 .		
Symbol	Value	Unit
R _{th1}	4.95E-01	
R _{th2}	2.26E+00	K/W
R _{th3}	2.14E+00	

Symbol	Value	Unit
C_{th1}	2.20E-04	
C_{th2}	1.13E-03	Ws/K
C _{th3}	2.85E-01	



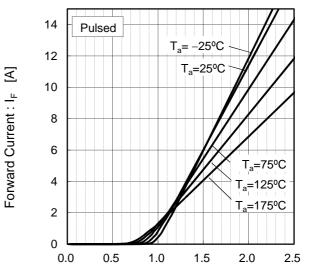
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



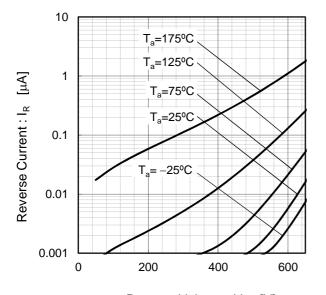
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



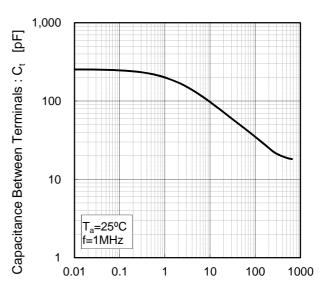
Forward Voltage: V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage: V_R [V]

Fig.4 V_R-C_t Characteristics



Reverse Voltage: V_R [V]

Electrical characteristic curves

vs. Pulse Width Transient Thermal Resistance : R_{th(j-c)} [°C/W] 10 T_a=25°C Single Pulse

Fig.5 Typical Transient Thermal Resistance

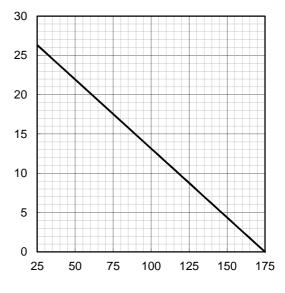
0.1 0.01 1.E-6 1.E-5 1.E-4 1.E-3 1.E-2 1.E-1 1.E+0 1.E+1

Pulse Width: PW [s]

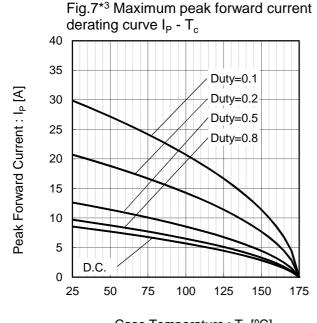
Fig.6 Power Dissipation

Power Dissipation [W]

Peak Forward Current : Ip [A]

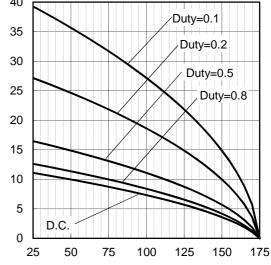


Case Temperature : T_c [°C]



Case Temperature : T_c [°C] *3 Based on max Vf, max $R_{\text{th(j-c)}}$ Valid for switching of above 10kHz, excluding D.C. curve.

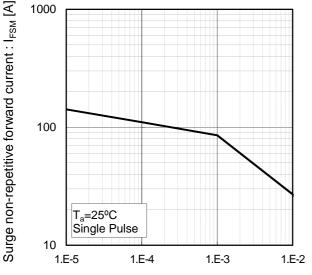
Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed) 40



Case Temperature : T_c [°C] $^{\star}4$ Based on typ Vf, typ $R_{\text{th(j-c)}}$ Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

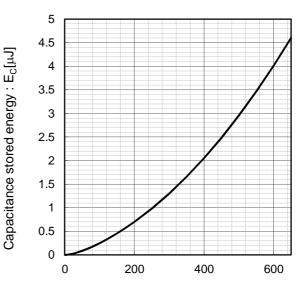
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

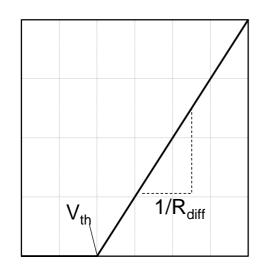
Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a ₀	9.66E-01	V
a ₁	-1.10E-03	V/°C
b ₀	8.80E-02	Ω
b ₁	1.87E-04	Ω/°C
b ₂	1.92E-06	$\Omega/^{\circ}C^{2}$

 $T_i \text{ in } {}^{\circ}\text{C}; -55 {}^{\circ}\text{C} < T_i < 175 {}^{\circ}\text{C}; I_F < 8 \text{ A}$

Forward Current: IF

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SCS304AM - Web Page

Distribution Inventory

Part Number	SCS304AM
Package	TO-220FM
Unit Quantity	1000
Minimum Package Quantity	50
Packing Type	Tube
Constitution Materials List	inquiry
RoHS	Yes

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